



Features

- SC-Cut resonator
- Frequency Range: 5 MHZ to 15 MHZ
- Low Package Height
- Temperature stability to 0.4 ppb
- Aging rate 0.1 ppb/day
- Frequency range 5 to 20 MHz
- Standard frequencies: 5, 10, 20 MHz

Applications

- LTE, LTE-A
- Test and Measurement Equipment
- Broadcast Reference Standard
- Satcom terminals

Performance Specifications

Frequency Stabilities ¹ (Stabilities listed for 10 MHz. For stabilities above 10 MHz values may degrade. Please contact factory)					
Parameter	Min	Min Typ Max Units Condition			
vs. operating temperature range (referenced to +25°C)	-0.2 -0.4 -0.6		+0.2 +0.4 +0.6	ppb ppb ppb	0 +70°C -20 +70°C -40 +85°C (+5V version)
	For better stability refer to the MX-042 datasheet.				
Initial Tolerance vs. supply voltage change vs. load change vs aging/ day vs aging/ day vs. aging / 1 year vs. aging / year (following years) vs. aging/ 10 years Retrace ²	-50 -0.1 -0.1 -1 -0.06 -20 -10 -75		+50 +0.1 +0.1 +1 +0.06 +20 +10 +75	ppb ppb ppb ppb ppb ppb ppb	at time of shipment, nominal EFC VS ± 5% Load ± 5% after 24 hours of operation after 72 hours of operation after 72 hours of operation after 72 hours of operation
Warm-up Time	İ		5	minutes	to ± 10 ppb of final frequency (1 hour) @25°C
Supply Voltage (Vs)					
Supply voltage (Standard)	4.75	5.0	5.25	VDC	
Supply voltage (Option)	11.4	12.0	12.6	VDC	

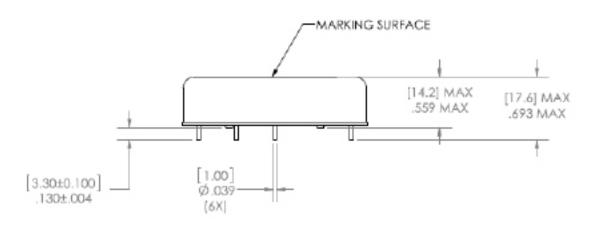
Performance Specifications

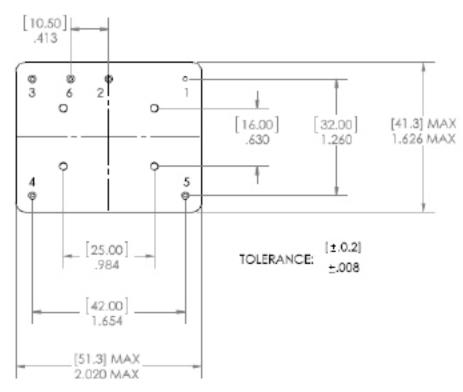
Supply Voltage (Vs)					
Parameter	Min	Typical	Max	Units	Condition
Cupply Voltage	4.75	5.0	5.25	VDC	Ordering code D
Supply Voltage	11.4	12.0	12.6	VDC	Ordering code B , temp stability T and J only
			5.0	Watts	during warm-up, all temperatures
Power Consumption eference Voltage (Vref) - when			2.0	Watts	steady state @ +25°C
specified for custom units.		4.0		Watts	steady state @ -40°C
·		1.0		Watts	steady state @ +85°C
			RF Output	t	
Start Time		1	2	S	time required to achieve 90% of amplitude
Signal [standard]		HCI	MOS		
Load		15		рF	
Signal Level (Vol)			0.5	VDC	
Signal Level (Voh)	3.5			VDC	
Duty Cycle	45		55	%	@ (Voh-Vol)/2
Signal	Sine Wave				
Load		50		Ω	
Output Power @ 5.0V,12 V	+5	+7	+9	dBm	
Harmonics			-40	dBc	
Subharmonics			-40	dBc	frequencies >= 10 MHz
		Frequ	iency Tunin	g (EFC)	
Tuning range	±150		±250	ppb	(fixed frequency option available)
Linearity		5		%	
Tuning Slope		Pos	itive		
Input Impedance		100		kOhm	
Bandwidth Modulation	150			Hz	
Control Voltago Pango	0.0	2.5	5	VDC	with Vs=12.0 VDC
Control Voltage Range	0.0	2.0	4.0	VDC	with Vs=5.0 VDC
Reference Voltage Output (Vref) the MX-060 can be conffigured with a reference voltage on pin 2. This configuration requires a custom part number. Please contact the factory for ordering information.					
Reference Voltage (Vref) - when	4.9	5	5.1	VDC	with Vs =12.0 VDC
specified for custom units	3.92	4.0	4.08	VDC	with Vs = 5.0 VDC

Additional Parameters						
Parameter	Min	Typical	Max	Units	Condition	
Phase noise ³			-95 -125 -140 -145 -145	dBc/Hz dBc/Hz dBc/Hz dBc/Hz dBc/Hz	1 Hz 10 Hz 100 Hz 1 kHz 10 kHz	@ 10MHz
For lower phase noise, please revi	For lower phase noise, please review the OX-174 or OX-204 datasheet.					
Allan Deviation			3e-12 5e-12 1e-11 5e-11		1 s tau 10 s tau 100 s tau 1000 s tau	@ 10MHz
For oscillators with lower ADEV re For oscillators with TDEV and MTI						
g-sensitivity				1	ppb/g	
g-sensitivity of 0.5 ppb/g availabl For g-sensitivity <0.5 ppb/g, plea				tory for orderin	g information.	
Weight			55	g		
Absolute Maximum Ratings						
			15.0	VDC		
Output load	25		50 open	pF Ohms	CMOS Sine	
Operable temperature range	-55		+95	°	Operable temperature range implies the device will continue to operate with no long-term damage to unit; however, it will not be specification compliant outside the operating temperature range.	
Environmental and Product Classification						
Shock (Endurance)	MIL-STD-202,	Method 213	, Condition J	. 30g 11 ms		
Sine Vibration (Endurance)	MIL-STD-202, Method 201 and 204, Condition A, except 5g to 500 Hz, 1 sweep each axis					
Random Vibration (Endurance)	MIL-STD-202, Method 214, Condition I-D					
Humidity	MIL-STD-202, Method 103, Condition B, 100% rh					
Seal	MIL-STD-202, Method 112, Condition D, hermetic, washable					
Altitude	MIL-STD-202, Method 105, sea level to space					
Resistance to Soldering Heat	MIL-STD-202, Method 210, Condition A,B,C					
Terminal Strength	MIL-STD-202, Method 211, Condition C (5 bends at 45°, 2 lbs)					
Moisture Sensitive Level	1					
RoHS	6 (fully compliant)					
Storage Temperature Range	-55		+125	°C		

Outline Drawing / Enclosure

Dimensions in inches, [] in mm.

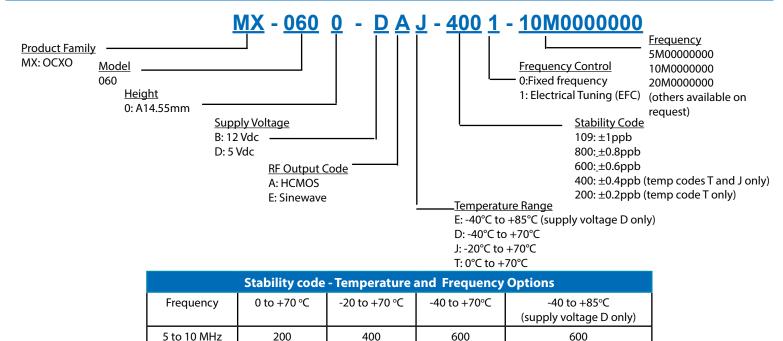




Type A						
Code	Height "H"	Pin Length "L"				
0	14.55	7.5				

	Pin Connections			
1	Electronic Frequency Control (EFC)			
2	N/C Optional Reference Voltage			
3	RF Output			
4	Ground (Case)			
5	Supply Voltage Input (Vs)			

Ordering Information



200 400 600 600 400 600 800 109

Additional Ordering Options

Additional ordering options available include custom heights, custom aging rates, custom temperature ranges, custom temperature stabilities, custom phase noise requirements, improved g-sensitivity, and oscillators with voltage reference output on pin 2. These modifications require a custom dash number - please contact the factory for additional information.

Design Tools

Microsemi stocks the following items for small orders and prototype development:
MX-0600-DEE-6001-10M0000000
Microsemi stocks the following evaluation board for this product:
OCXO Evaluation Board
Application Notes:
None

Notes:

- Unless otherwise stated, all values are valid after warm-up time and refer to typical conditions for supply voltage, frequency control voltage, load, and temperature (25°C).
- 2. Retrace defined as f1-fo where fo is the reading after the unit has been on power for 24 hours, and f1 is the frequency after 24 hours off followed by 60 minutes on.
- 3. Phase noise degrades with increasing output frequency.
- 4. Not all options and codes available at all frequencies.

> 10 MHz



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